# NSN 5961-01-017-6026

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Inclosure Material: Metal

**Overall Length:** 

0.077 inches

**Overall Diameter:** 

0.165 inches

Internal Configuration:

Junction contact

**Mounting Method:** 

Press fit

**Features Provided:** 

Hermetically sealed case

Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

20.0 breakdown voltage, collector-to-base, emitter open and 12.0 breakdown voltage, collector-to-emitter, base open and 3.0 breakdown

voltage, emitter-to-base, collector open

### **Current Rating Per Characteristic:**

50.00 milliamperes source cutoff current

# **Power Rating Per Characteristic:**

300.0 milliwatts small-signal input power, common-collector

# Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

### **Special Features:**

Junction pattern arrangement: npn

## Terminal Type And Quantity:

4 ribbon

Shelf Life:

N/a

Unit Of Measure:

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#### **Demilitarization:**

No

# Fiig:

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